IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

| Priority Application Serial No | |
|--|---------------------------------|
| Priority Filing Date | January 10, 2003 |
| Inventor | Zhongze Wang |
| Assignee | Micron Technology, Inc. |
| Priority Group Art Unit | 2812 |
| Priority Examiner | |
| Attorney's Docket No | MI22-2457 |
| Customer No | |
| Title: Wafer Bonding Method of Forming Integrated Circuitry (as Amended) | Silicon-on-Insulator Comprising |
| integrated entediting (de / interrued/ | |

PRELIMINARY AMENDMENT

To: Mail Stop Patent Application

Commissioner for Patents

P. O. Box 1450

Alexandria, VA 22313-1450

VIA EXPRESS MAIL

From: Mark Matkin (Tel. 509-624-4276; Fax 509-838-3424)

Wells St. John P.S.

601 West First Avenue, Suite 1300

Spokane, WA 99201-3828

Please enter the following amendments prior to examining the aboveidentified application.

AMENDMENTS

Amendments to th Titl

Please change the title to the following: -- WAFER BONDING
METHOD OF FORMING SILICON-ON-INSULATOR COMPRISING
INTEGRATED CIRCUITRY --.

•